



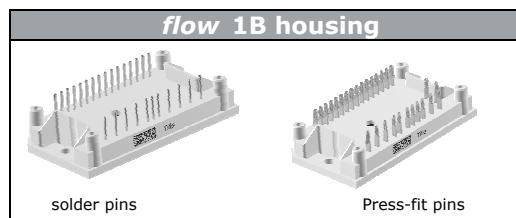
Vincotech

**20-1B06IPB004RC-P952A40**  
**20-PB06IPB004RC-P952A40Y**

datasheet

**flow IPM 1B****600 V / 4 A**

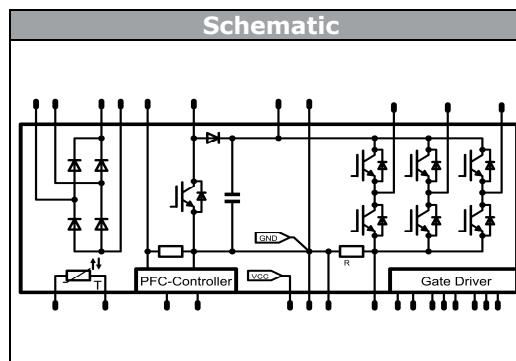
Features
<ul style="list-style-type: none"> <li>• Input Rectifier, PFC-Boost with integrated PFC-Shunt, PFC-Controller and DC-capacitor</li> <li>• 3 phase inverter with integrated DC Shunt, gate driver circuit incl. bootstrap circuit and over current protection</li> <li>• Sense output of DC-current</li> <li>• Temperature sensor</li> <li>• Conclusive Power Flow, all power connections on one side, no input output X-ing</li> </ul>



Target Applications
<ul style="list-style-type: none"> <li>• Low Power Industrial Drives</li> <li>• Motor Integrated Fans and Pumps</li> <li>• AirCon</li> <li>• Electrical Tools</li> </ul>

Types
<ul style="list-style-type: none"> <li>• 20-1B06IPB004RC-P952A40</li> <li>• 20-PB06IPB004RC-P952A40Y</li> </ul>

**Maximum Ratings** $T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Input Rectifier Diode</b>				
Repetitive peak reverse voltage	$V_{RRM}$		1600	V
DC forward current	$I_{FAV}$	$T_j = T_{jmax}$	13	A
Surge (non-repetitive) forward current	$I_{FSM}$	$t_p = 10 \text{ ms}$ 50 Hz half sine wave	130	A
$I^2t$ -value	$I^2t$	$T_j = 45^\circ\text{C}$	80	$\text{A}^2\text{s}$
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	15	W
Maximum Junction Temperature	$T_{jmax}$		150	$^\circ\text{C}$

**PFC IGBT**

Collector-emitter breakdown voltage	$V_{CE}$		650	V
DC collector current	$I_C$	$T_j = T_{jmax}$	8	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	45	A
Turn off safe operating area		$V_{CE} \leq 650\text{V}$ , $T_j \leq T_{op\ max}$	45	A
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	16	W
Gate-emitter peak voltage	$V_{GE}$		$\pm 20$	V
Maximum Junction Temperature	$T_{jmax}$		175	$^\circ\text{C}$



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## Maximum Ratings

 $T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>PFC Inverse Diode</b>				
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
DC forward current	$I_F$	$T_j = T_{jmax}$	6	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	12	A
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	10	W
Maximum Junction Temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>PFC Diode</b>				
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
DC forward current	$I_F$	$T_j = T_{jmax}$	9	A
Surge (non-repetitive) forward current	$I_{FSM}$	$t_p=8,3\text{ms}$ 60 Hz half sine wave	100	A
$I^2t$ -value	$I^2t$		40	$\text{A}^2\text{s}$
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	30	A
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	15	W
Maximum Junction Temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Inverter Transistor</b>				
Collector-emitter breakdown voltage	$V_{CE}$		600	V
DC collector current	$I_C$	$T_j = T_{jmax}$	4	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	12	A
Turn off safe operating area		$V_{CE} \leq 600\text{V}$ , $T_j \leq T_{jmax}$	8	A
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	12	W
Gate-emitter peak voltage	$V_{GE}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$ $V_{CC}$	$T_j \leq 150^\circ\text{C}$ $V_{GE} = 15\text{ V}$	8 400	$\mu\text{s}$ V
Maximum Junction Temperature	$T_{jmax}$		175	$^\circ\text{C}$



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Inverter Diode</b>				
Peak Repetitive Reverse Voltage	$V_{RRM}$		600	V
DC forward current	$I_F$	$T_j = T_{jmax}$	5	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	8	A
Power dissipation	$P_{tot}$	$T_j = T_{jmax}$	9	W
Maximum Junction Temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>PFC Shunt</b>				
DC forward current	$I_F$	$T_c = 25^\circ\text{C}$	10	A
Power dissipation	$P_{tot}$	$T_c = 25^\circ\text{C}$	9	W
<b>PFC Controller*</b>				
VCC supply voltage	$V_{CC}$	$V_{CC}$ common with gate driver $I_C$	26	V
VSENSE voltage	$V_{VSENSE}$		26	V
Vsense Current	$I_{VSENSE}$		800	$\mu\text{A}$
FREQ pin voltage	$V_{FREQ}$		5,3	V
Maximum Junction Temperature	$T_{jmax}$		125	$^\circ\text{C}$
* for more information see Infineon's datasheet ICE3PCS02				
<b>DC - Shunt</b>				
DC forward current	$I_F$	$T_c = 25^\circ\text{C}$	8	A
Power dissipation	$P_{tot}$	$T_c = 25^\circ\text{C}$	3,2	W
<b>DC link Capacitor</b>				
Max.DC voltage	$V_{MAX}$	$T_c = 25^\circ\text{C}$	500	V
<b>Gate Driver*</b>				
Supply voltage	$V_{CC}$	$V_{CC}$ common with PFC driver	20	V
Input voltage (LIN, HIN, EN)	$U_{IN}$		10	V
Output voltage (FAULT)	$U_{OUT}$		$V_{CC} + 0.5$	V
* for more information see infineon's datasheet 6ED003L02-F2				

## Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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### Thermal Properties

Storage temperature	$T_{\text{stg}}$		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	$T_{\text{op}}$		-40...+( $T_{\text{jmax}} - 25$ )	$^\circ\text{C}$

### Isolation Properties

Isolation voltage	$V_{\text{is}}$	$t = 2 \text{ s}$	DC Test Voltage	4000	$\text{V}$
Creepage distance				min 12,7	mm
Clearance				min 12,7	mm
Comparative tracking index	CTI			>200	



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		$V_{GE}$ [V]	$V_r$ [V]	$I_C$ [A]	$I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		
		$V_{GS}$ [V]	$V_{CE}$ [V]	$I_D$ [A]							

## Input Rectifier Diode

Forward voltage *	$V_F$			7	25 125			1,04 0,97			V
Threshold voltage (for power loss calc. only)	$V_{to}$			7	25 125			0,87 0,74			V
Slope resistance (for power loss calc. only)	$r_t$			7	25 125			25 33			mΩ
Reverse current	$I_r$		1600		25 125				0,01		mA
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						4,56			K/W

\* chip data

## PFC IGBT

Gate emitter threshold voltage	$V_{GE(\text{th})}$	$V_{GE} = V_{CE}$		0,0004	25		3,3	4	4,7		V
Collector-emitter saturation voltage*	$V_{CESat}$		15	6	25 150			1,43 1,55	2,05		V
Collector-emitter cut-off	$I_{CES}$		0	650		25			0,04		mA
Rise time	$t_r$				25 150			2 2			
Turn-off delay time **	$t_{d(\text{off})}$				25 150			107 161			ns
Fall time	$t_f$				25 150			4			
Turn-on energy loss	$E_{on}$				25 150			0,055 0,091			mWs
Turn-off energy loss	$E_{off}$				25 150			0,020 0,038			
Input capacitance	$C_{ies}$							930			
Output capacitance	$C_{oss}$	$f = 1 \text{ MHz}$	0	25		25		24			pF
Reverse transfer capacitance	$C_{rss}$							4			
Gate charge	$Q_G$		±15	520	15	25		38			nC
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						5,80			K/W

\* chip data

## PFC Inverse Diode

Diode forward voltage	$V_F$			6	25 125		1,23	1,73 1,59	2,15		V
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						9,56			K/W

## PFC Diode

Forward voltage *	$V_F$			6	25 150			1,51 1,42	2,13		V
Peak recovery current	$I_{RRM}$				25 150			11 13			A
Reverse recovery time	$t_{rr}$				25 150			18 28			ns
Reverse recovery charge	$Q_{rr}$				25 150			0,12 0,24			μC
Reverse recovered energy	$E_{rec}$				25 150			0,013 0,033			mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$				25 150			959 452			A/μs
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						7,19			K/W

\* chip data

## PFC Shunt

R1 value	$R$							100			mΩ
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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		$V_{GE}$ [V]	$V_r$ [V]	$I_C$ [A]	$I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		
		$V_{GS}$ [V]	$V_{CE}$ [V]	$I_D$ [A]							

## Inverter Transistor

Gate emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,000075	25	4,4	5	5,6	V
Collector-emitter saturation voltage*	$V_{CESat}$		15		4	25 150	1,7	2,20 2,29	2,8	V
Collector-emitter cut-off current incl. Diode	$I_{CES}$		0	600		25			0,1	mA
Gate-emitter leakage current	$I_{GES}$		20	0		25			120	nA
Integrated Gate resistor	$R_{git}$							none		Ω
Turn-on delay time **	$t_{d(on)}$	$U_{CC}=15V$ $V_{IN}=5V$	400	4		25 150		586 635		ns
Rise time	$t_r$					25 150		21 30		
Turn-off delay time **	$t_{d(off)}$					25 150		666 749		
Fall time	$t_f$					25 150		20 50		
Turn-on energy loss	$E_{on}$					25 150		0,117 0,198		mWs
Turn-off energy loss	$E_{off}$					25 150		0,072 0,115		
Input capacitance	$C_{ies}$							305		
Output capacitance	$C_{oss}$	$f = 1 \text{ MHz}$	0	25		25		18		pF
Reverse transfer capacitance	$C_{rss}$							9		
Thermal resistance junction to sink	$R_{th(j-s)}$							8,93		K/W

\* chip data

\*\* including gate driver

## Inverter Diode

Diode forward voltage *	$V_F$				4	25 150	1,5	2,08 1,92	2,6	V
Peak reverse recovery current	$I_{RRM}$	$U_{CC}=15V$ $V_{IN}=5V$	400	4		25 150		2 3		A
Reverse recovery time	$t_{rr}$					25 150		166 254		
Reverse recovered charge	$Q_r$					25 150		0,18 0,35		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 150		25 16		
Reverse recovered energy	$E_{rec}$					25 150		0,045 0,085		
Thermal resistance junction to sink	$R_{th(j-s)}$							10,05		K/W

\* chip data

## DC - Shunt

R2 value	$R$					25		50		$m\Omega$
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## DC link Capacitor

C value	$C$							100		$nF$
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datasheet

## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		$V_{GE}$ [V]	$V_r$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max			
		$V_{GS}$ [V]	$V_{CE}$ [V]	$I_F$ [A]	$I_D$ [A]						
<b>Gate Driver</b>											
Supply voltage	$V_{CC}$			25 125		13	15	17,5			V
Quiescent $V_{CC}$ supply current	IQCC	$V_{LIN}=0V; VHIN=3,3V$			25 125		1,3	2			mA
Input voltage (LIN, HIN, EN)	VIN	$V_{CC} = 15V$		25 125		0		5			V
Input voltage (GATE)	VGATE			25 125		0		15			
Logic "0" input voltage (LIN, HIN)	VIH			25 125		1,7	2,1	2,4			
Logic "1" input voltage (LIN, HIN)	VIL			25 125		0,7	0,9	1,1			
Positive going threshold voltage (EN)	VEN, TH+			25 125		1,9	2,1	2,3			
Negative going threshold voltage (EN)	VEN, TH-			25 125		1,1	1,3	1,5			
Input clamp voltage (LIN, HIN, EN)	VIN, CLAMP		IIN = 4mA	25 125		9	10,3	12			
ITRIP positive going threshold	VIT, TH+			25 125		380	445	510			mV
Input bias current LIN high	$I_{IIN+}$	$V_{LIN} = 3,3V$			25 125		70	100			μA
Input bias current LIN low	$I_{IIN-}$	$V_{LIN} = 0V$			25 125		110	200			
Input bias current HIN high	$I_{HIN+}$	$V_{HIN} = 3,3V$			25 125		70	100			
Input bias current HIN low	$I_{HIN-}$	$V_{HIN} = 0V$			25 125		110	200			
Input bias current EN high	IEN+	$V_{HIN} = 3,3V$			25 125		45	120			
Output voltage (FAULT)	$V_{FLT}$			25 125		0		$V_{CC}$			V
Low on resistor of pull down trans. (FAULT)	RON, FLT	$V_{FAULT}=0.5 V$			25 125		45	100			Ω
Pulse width for ON or OFF	tIN			25 125		1					μs
Turn-on propagation delay (LIN, HIN)	tON	$V_{LIN/HIN} = 0V \text{ or } 3,3V$			25 125		400	530	800		ns
Turn-off propagation delay (LIN, HIN)	tOFF	$V_{LIN/HIN} = 0V \text{ or } 3,3V$			25 125		360	490	760		
FAULT reset time	tRST			25 125			4				ms
Fixed deadtime between high and low side	tDT	$V_{LIN/HIN} = 0V \& 3,3V$			25 125		150	310			ns



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## Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		$V_{GE}$ [V]	$V_r$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max			
		$V_{GS}$ [V]	$V_{CE}$ [V]	$I_F$ [A]	$I_D$ [A]						

## Thermistor

Rated resistance	R		25		22000		$\Omega$
Deviation of $R_{100}$	$\Delta R/R$		100	-12	12		%
Power dissipation	P		25		200		mW
Power dissipation constant			25		2		mW/K
B-value	$B_{(25/50)}$	Tol. ±3%	25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%	25		3998		K
Vincotech NTC Reference			25			B	

## PFC Controller

Supply voltage*	$V_{CC}$		25	15		26	V	
VCC turn-on threshold	$V_{CCon}$			11,5	12,0	12,9		
VCC turn-off threshold	$V_{CCUVLO}$			10,5	11,0	11,9		
Operating current with active GATE	$I_{CCHG}$	$C_L=1nF$			6,4	8,5		
Operating current during standby	$I_{CCStby}$				3,5	4,7		
PFC switching frequency	$F_{SWnom}$	Set with an internal resistor $R_{FREQ}=220k\Omega^{**}$			20			
PFC disable threshold	$V_{dis\ PFC}$	pull Vsense higher than $V_{dis\ PFC}$ to disable PFC operation		14				
DC link voltage	DC2+	Set with an internal resistor divider***		325		410		
DC link threshold (OVP1) low to high	$V_{OVP1L2H}$	relative to output voltage OVP1 values varies with external resistor Feedback voltage $V_{DClink}/130$ can be measured at VSENSE pin			108			
DC link threshold (OVP1) high to low	$V_{OVP1H2L}$				100			
Blanking time for OVP1	$t_{OVP1}$				12		μs	
DC link threshold (OVP1) hysteresis	$V_{OVP1\_HYS}$			6	8	11	%	
DC link threshold (OVP2) low to high	$V_{OVP2\_L2H}$			428	443	460	V	
DC link threshold (OVP2) high to low	$V_{OVP2\_H2L}$	relative to OVP2			92		%	
Blanking time for OVP2	$t_{OVP2}$				12		μs	

\*recommended supply voltage range: 15-18 V

\*\*switching frequency is setable by an external resistor between pins 14-16 (see figure on page30 for values)

\*\*\*DC link voltage is setable by an external resistor between pins 14-15 (see figure on page30 for values)



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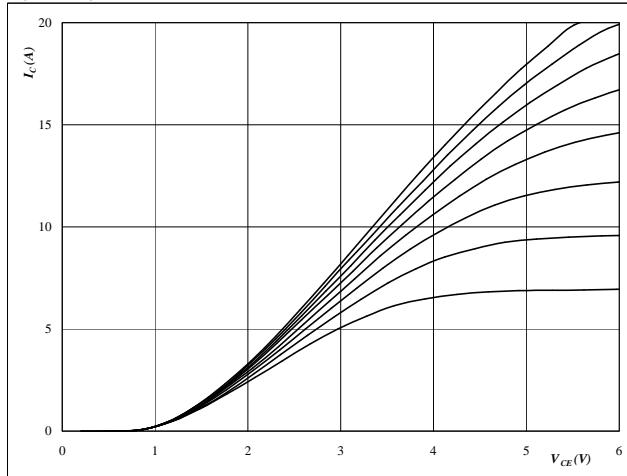
## Output Inverter

**figure 1.**

**Typical output characteristics**

**IGBT**

$$I_C = f(V_{CE})$$



**At**

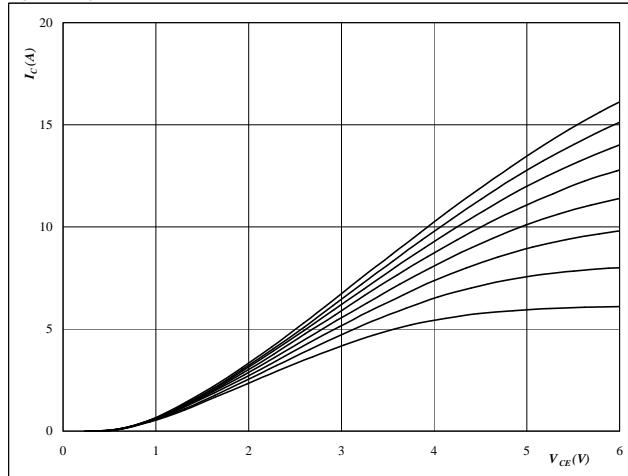
$t_p = 250 \mu\text{s}$   
 $T_j = 25^\circ\text{C}$   
 $U_{CC}$  from 10 V to 17V in steps of 1V

**figure 2.**

**Typical output characteristics**

**IGBT**

$$I_C = f(V_{CE})$$



**At**

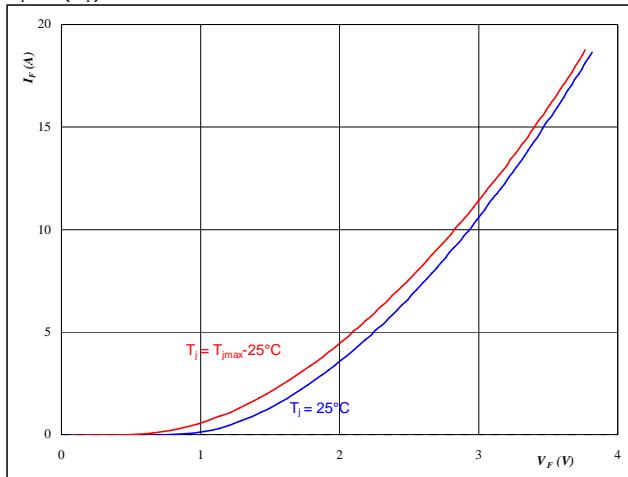
$t_p = 250 \mu\text{s}$   
 $T_j = 125^\circ\text{C}$   
 $U_{CC}$  from 10 V to 17V in steps of 1V

**figure 3.**

**FWD**

**Typical diode forward current as a function of forward voltage**

$$I_F = f(V_F)$$



**At**

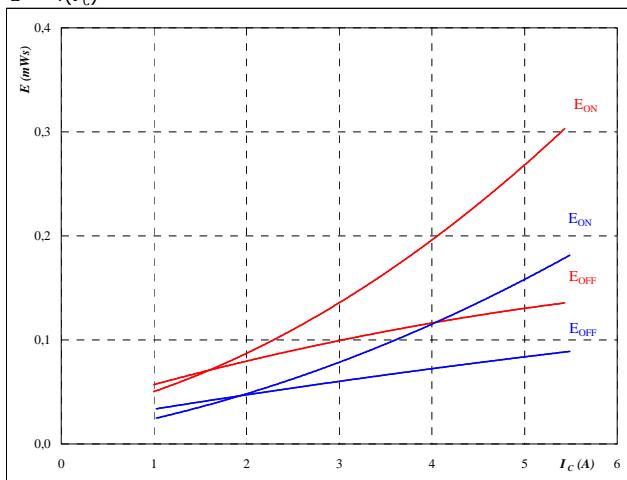
$t_p = 250 \mu\text{s}$

## Output Inverter

**figure 4.****IGBT**

**Typical switching energy losses  
as a function of collector current**

$$E = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

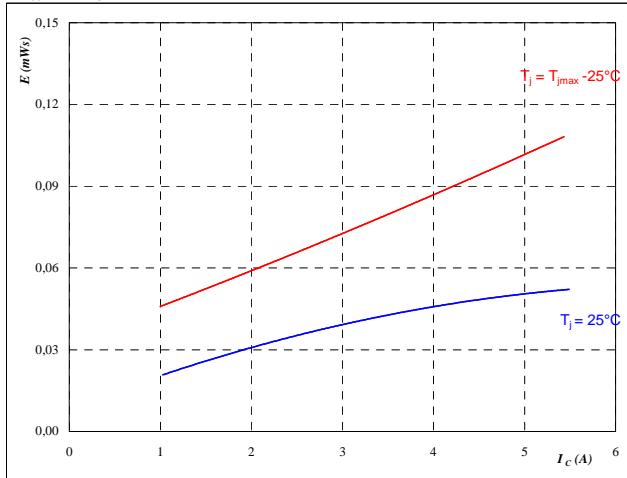
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

**figure 5.****FWD**

**Typical reverse recovery energy loss  
as a function of collector current**

$$E_{rec} = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

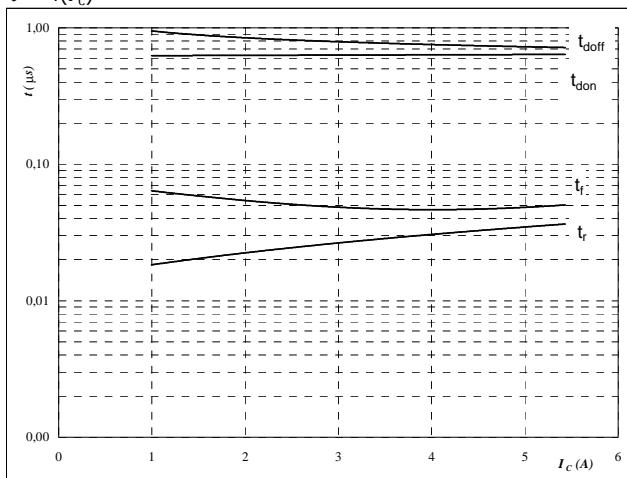
$$U_{CC} = 15 \quad \text{V}$$

## Output Inverter

**figure 6.****IGBT**

**Typical switching times as a function of collector current**

$$t = f(I_c)$$



With an inductive load at

$$T_j = 125 \quad ^\circ\text{C}$$

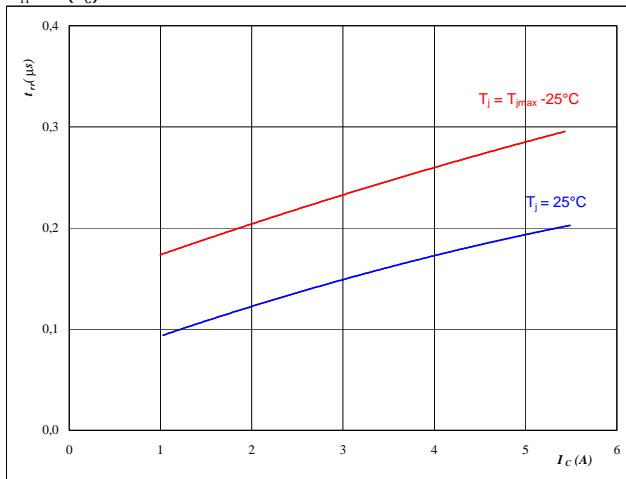
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

**figure 7.****FWD**

**Typical reverse recovery time as a function of collector current**

$$t_{rr} = f(I_c)$$



**At**

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

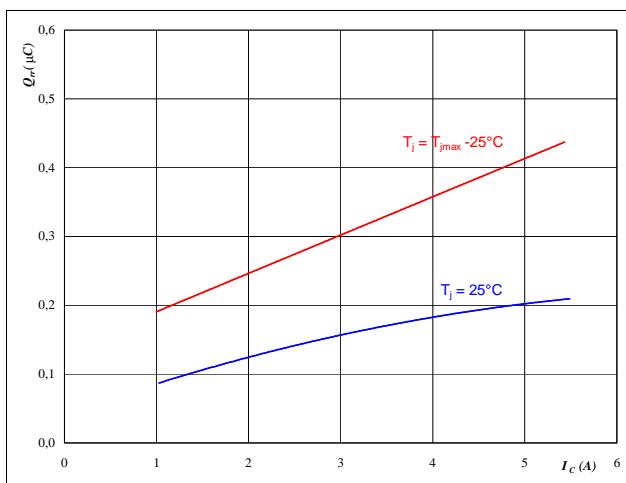
$$U_{CC} = 15 \quad \text{V}$$

## Output Inverter

**figure 8.****FWD**

**Typical reverse recovery charge as a function of collector current**

$$Q_{rr} = f(I_c)$$

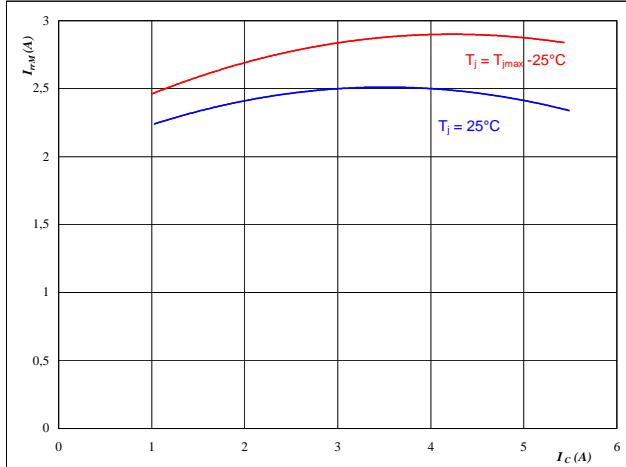
**At**

$T_j = 25/125 \quad ^\circ\text{C}$   
 $V_{CE} = 400 \quad \text{V}$   
 $U_{CC} = 15 \quad \text{V}$

**figure 9.****FWD**

**Typical reverse recovery current as a function of collector current**

$$I_{RRM} = f(I_c)$$

**At**

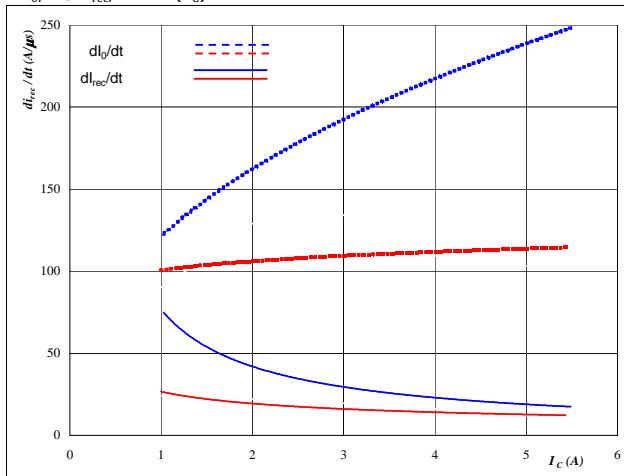
$T_j = 25/125 \quad ^\circ\text{C}$   
 $V_{CE} = 400 \quad \text{V}$   
 $U_{CC} = 15 \quad \text{V}$

## Output Inverter

**figure 10.****FWD**

**Typical rate of fall of forward  
and reverse recovery current as a  
function of collector current**

$$dI_0/dt, dI_{rec}/dt = f(I_c)$$

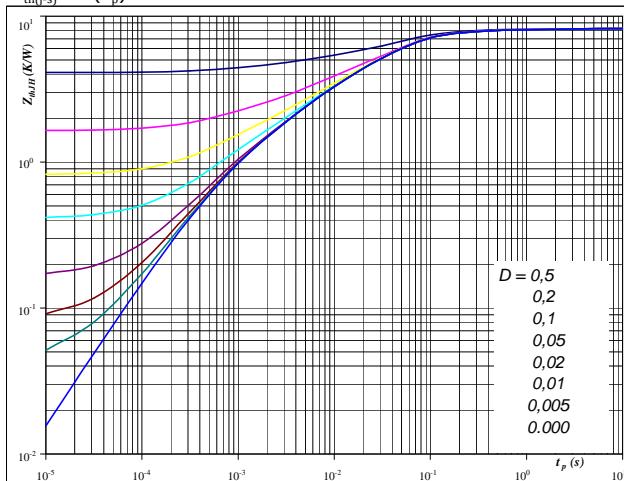
**At**

$T_j = 25/125 \text{ } ^\circ\text{C}$   
 $V_{CE} = 400 \text{ V}$   
 $U_{CC} = 15 \text{ V}$

**figure 11.****IGBT**

**IGBT transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$

**At**

$D = t_p / T$   
 $R_{th(j-s)} = 8,20 \text{ K/W}$

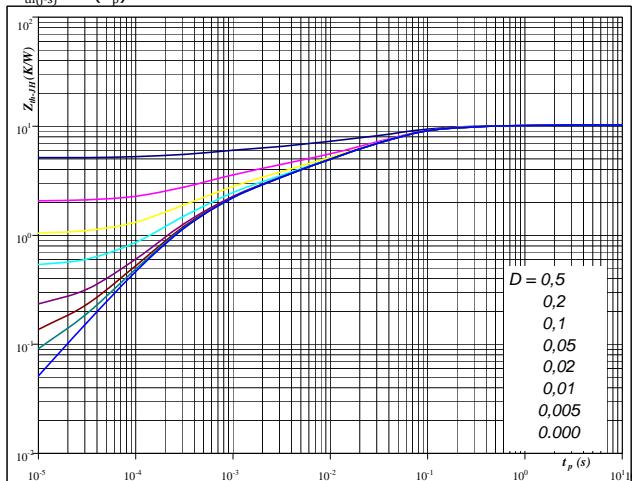
IGBT thermal model values

$R$ (K/W)	Tau (s)
2,49E-01	1,64E+00
9,97E-01	1,59E-01
4,55E+00	3,81E-02
1,65E+00	5,10E-03
6,64E-01	7,96E-04
9,00E-02	3,11E-04

**figure 12.****FWD**

**FWD transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$

**At**

$D = t_p / T$   
 $R_{th(j-s)} = 10,24 \text{ K/W}$

FWD thermal model values

$R$ (K/W)	Tau (s)
5,43E-01	6,92E-01
3,81E+00	5,93E-02
2,56E+00	1,81E-02
1,83E+00	2,58E-03
1,50E+00	3,50E-04



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datasheet

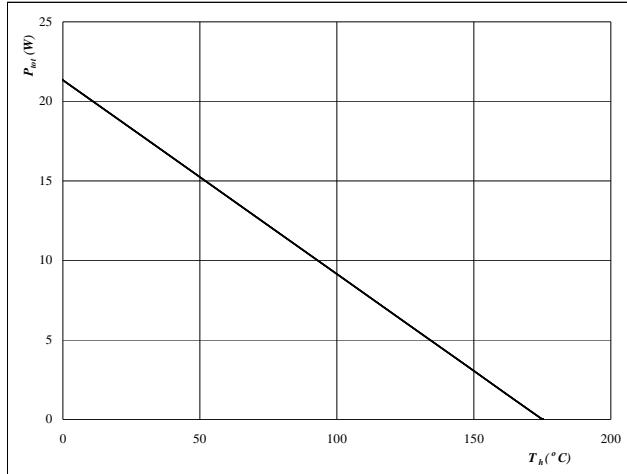
## Output Inverter

figure 13.

IGBT

**Power dissipation as a function of heatsink temperature**

$$P_{\text{tot}} = f(T_s)$$

**At**

$$T_j = 175 \quad {}^\circ\text{C}$$

figure 15.

FWD

**Power dissipation as a function of heatsink temperature**

$$P_{\text{tot}} = f(T_s)$$

**At**

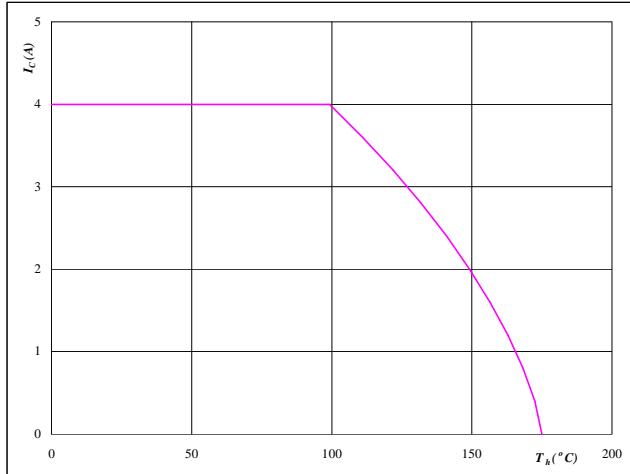
$$T_j = 175 \quad {}^\circ\text{C}$$

figure 14.

IGBT

**Collector current as a function of heatsink temperature**

$$I_C = f(T_s)$$

**At**

$$T_j = 175 \quad {}^\circ\text{C}$$

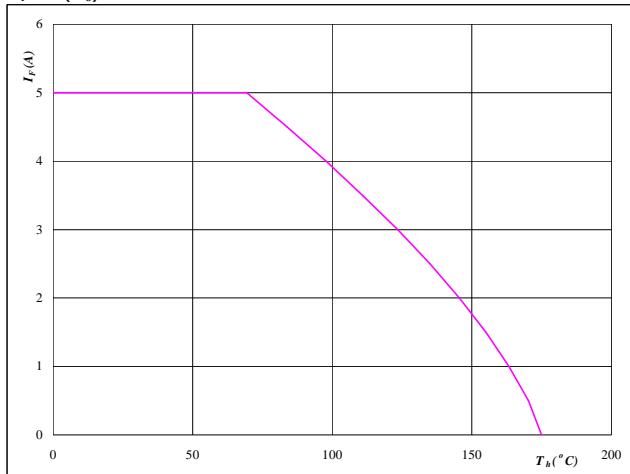
$$U_{CC} = 15 \quad \text{V}$$

figure 16.

FWD

**Forward current as a function of heatsink temperature**

$$I_F = f(T_s)$$

**At**

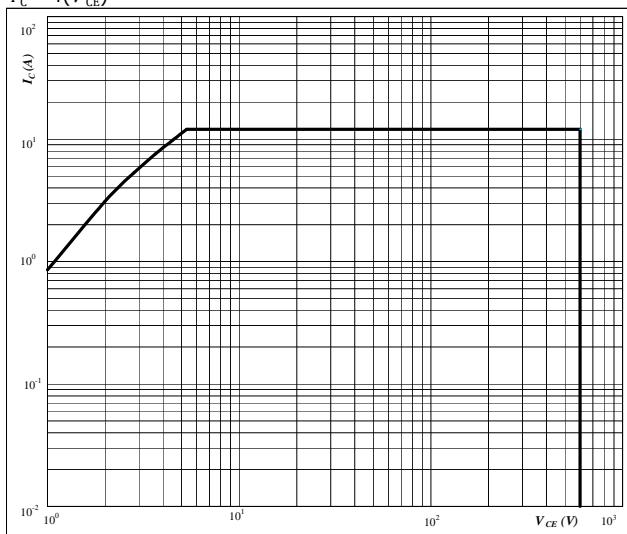
$$T_j = 175 \quad {}^\circ\text{C}$$

## Output Inverter

**figure 17.****IGBT**

**Safe operating area as a function  
of collector-emitter voltage**

$$I_C = f(V_{CE})$$

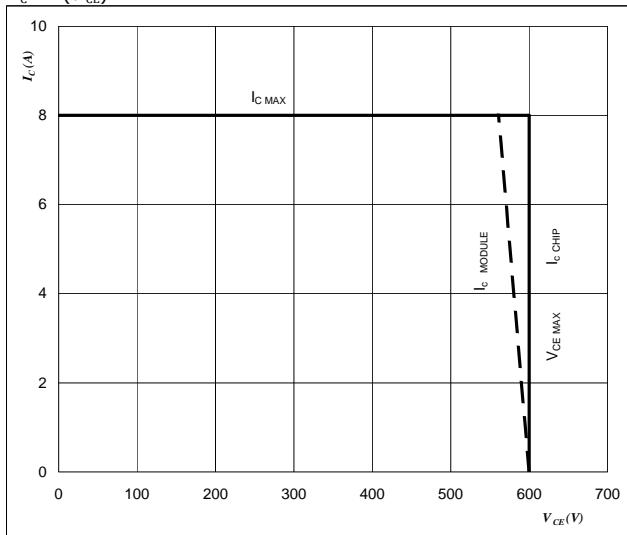
**At**

$$\begin{array}{lll} T_j \leq & T_{jmax} & {}^\circ\text{C} \\ U_{CC} = & 15 & \text{V} \end{array}$$

**figure 18.****IGBT**

**Reverse bias safe operating area**

$$I_C = f(V_{CE})$$

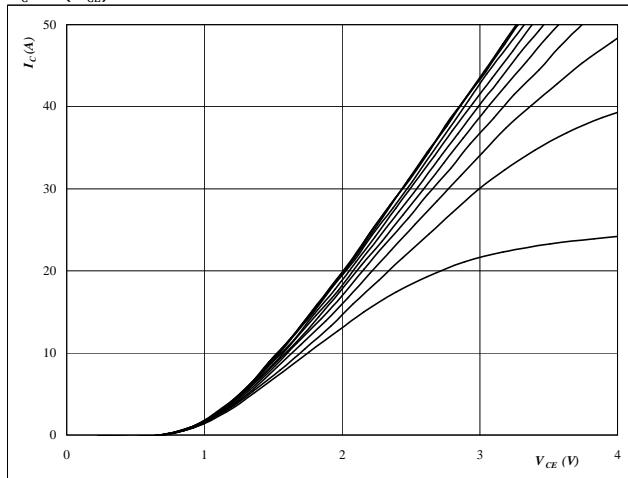
**At**

$$T_j = T_{jmax}-25 \quad {}^\circ\text{C}$$

## PFC

**figure 1.**
**IGBT**
**Typical output characteristics**

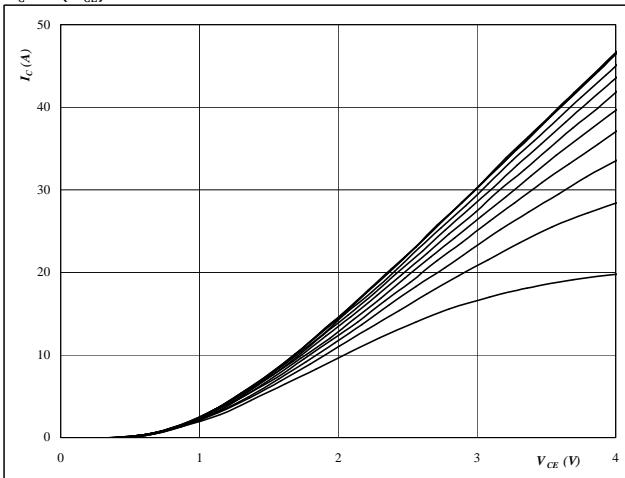
$$I_C = f(V_{CE})$$


**At**

$t_p =$	250	$\mu s$
$T_j =$	25	$^{\circ}C$
$U_{CC}$ from	7 V to	17V in steps of 1V

**figure 2.**
**IGBT**
**Typical output characteristics**

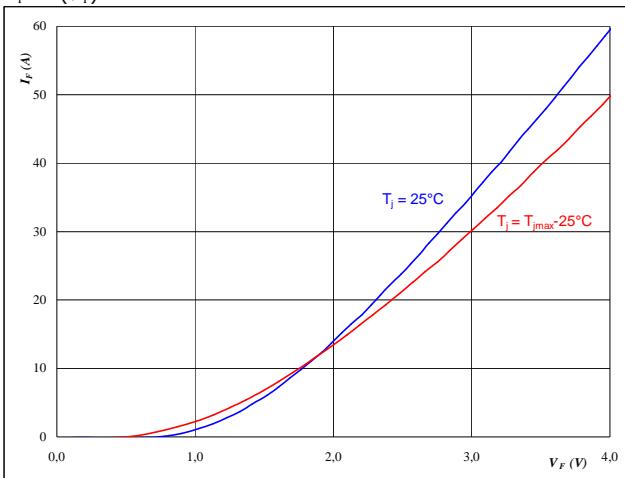
$$I_C = f(V_{CE})$$


**At**

$t_p =$	250	$\mu s$
$T_j =$	150	$^{\circ}C$
$U_{CC}$ from	7 V to	17V in steps of 1V

**figure 3.**
**FWD**
**Typical diode forward current as a function of forward voltage**

$$I_F = f(V_F)$$


**At**

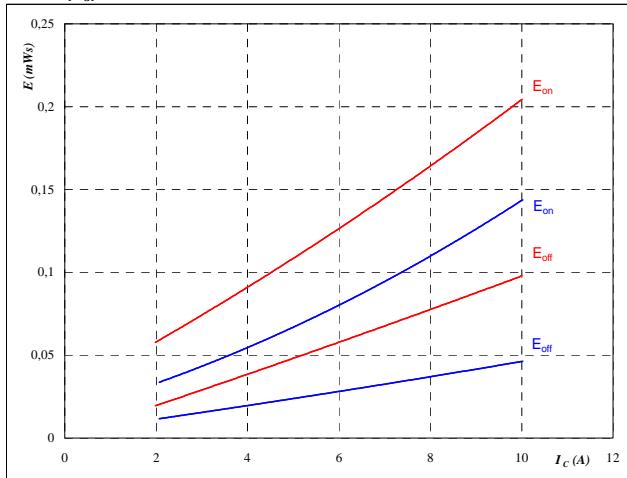
$t_p =$	250	$\mu s$
---------	-----	---------

## PFC

**figure 4.** **IGBT**

**Typical switching energy losses  
as a function of collector current**

$$E = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

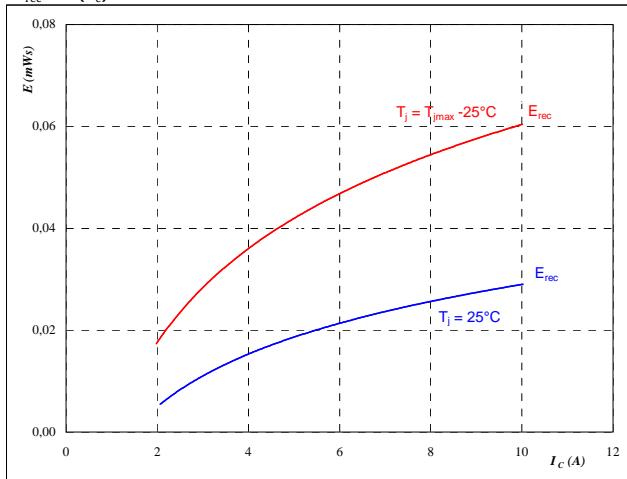
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

**figure 5.** **IGBT**

**Typical reverse recovery energy loss  
as a function of collector current**

$$E_{rec} = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

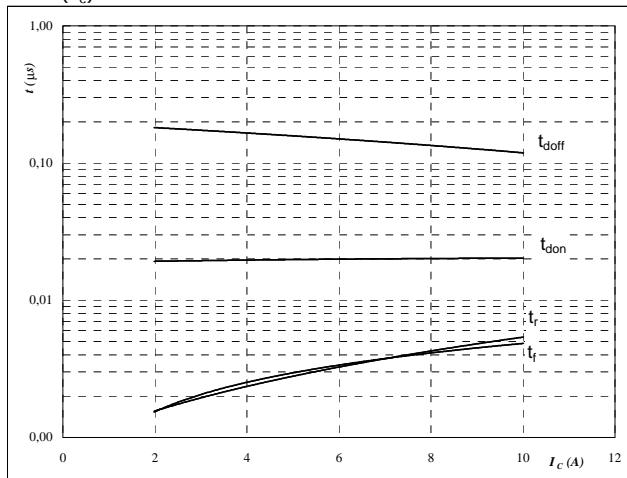
$$U_{CC} = 15 \quad \text{V}$$

## PFC

**figure 6.** IGBT

**Typical switching times as a function of collector current**

$$t = f(I_c)$$



With an inductive load at

$$T_j = 125 \text{ } ^\circ\text{C}$$

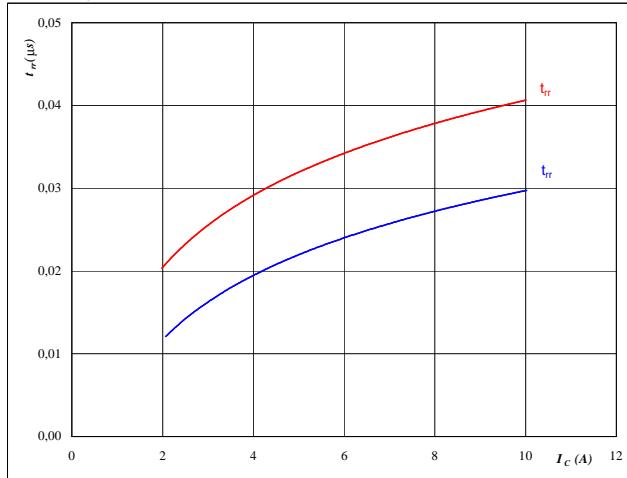
$$V_{CE} = 400 \text{ V}$$

$$U_{CC} = 15 \text{ V}$$

**figure 7.** FWD

**Typical reverse recovery time as a function of collector current**

$$t_{rr} = f(I_c)$$



At

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 400 \text{ V}$$

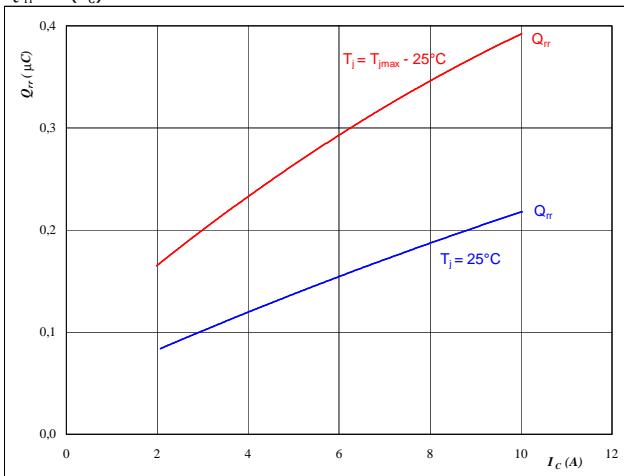
$$U_{CC} = 15 \text{ V}$$

## PFC

**figure 8.** FWD

Typical reverse recovery charge as a function of collector current

$$Q_{rr} = f(I_c)$$



**At**

$$T_j = 25/125 \quad {}^\circ\text{C}$$

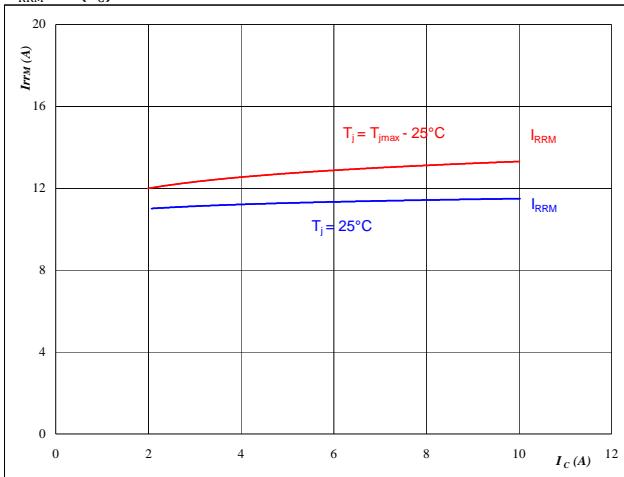
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

**figure 9.** FWD

Typical reverse recovery current as a function of collector current

$$I_{RRM} = f(I_c)$$



**At**

$$T_j = 25/125 \quad {}^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$



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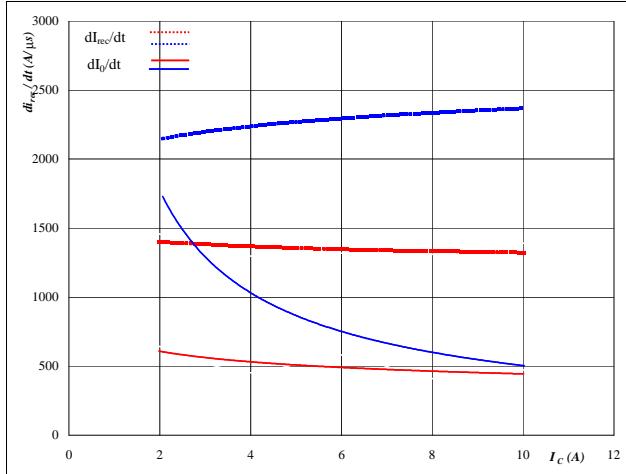
## PFC

**figure 10.**

**FWD**

**Typical rate of fall of forward  
and reverse recovery current as a  
function of collector current**

$$dI_0/dt, dI_{rec}/dt = f(I_c)$$



**At**

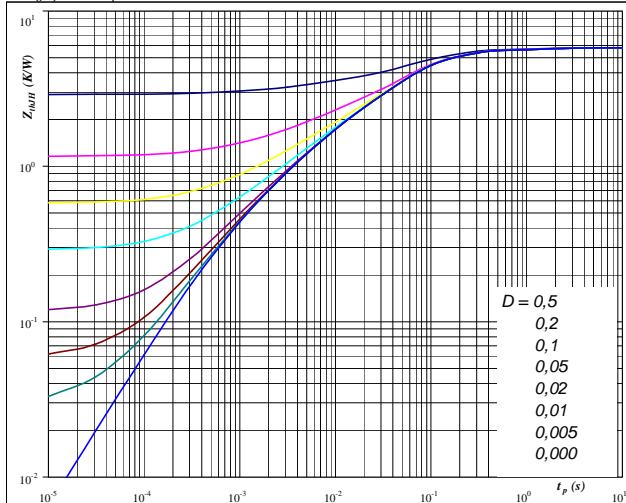
$T_j = 25/125 \text{ } ^\circ\text{C}$   
 $V_{CE} = 400 \text{ V}$   
 $U_{CC} = 15 \text{ V}$

**figure 11.**

**IGBT**

**IGBT transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$



**At**

$D = t_p / T$   
 $R_{th(j-s)} = 5,80 \text{ K/W}$

IGBT thermal model values

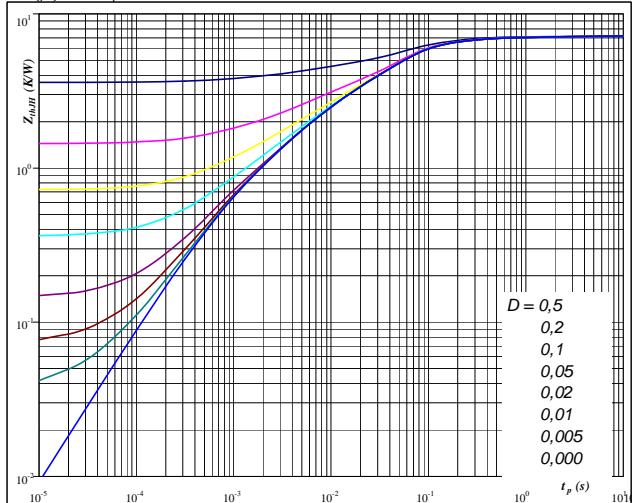
R (C/W)	Tau (s)
8,85E-02	4,38E+00
3,12E-01	8,32E-01
1,99E+00	1,12E-01
2,31E+00	3,80E-02
8,99E-01	4,25E-03
	5,94E-04

**figure 12.**

**FWD**

**FWD transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$



**At**

$D = t_p / T$   
 $R_{th(j-s)} = 7,19 \text{ K/W}$

FWD thermal model values

R (C/W)	Tau (s)
2,22E-01	2,69E+00
6,61E-01	2,71E-01
4,47E+00	4,89E-02
1,43E+00	5,11E-03
4,13E-01	7,51E-04



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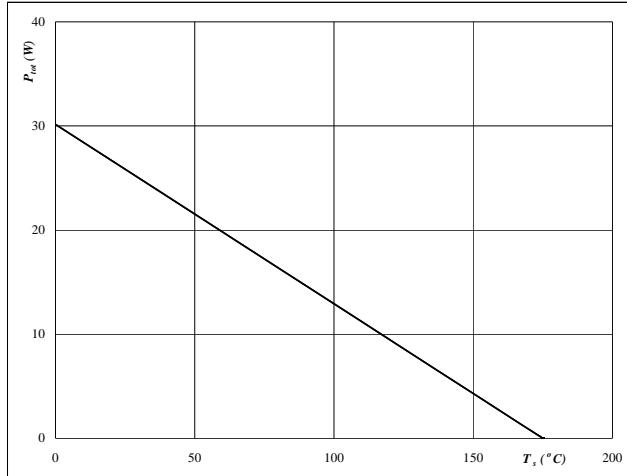
datasheet

## PFC

**figure 13.**

**Power dissipation as a function of heatsink temperature**

$$P_{\text{tot}} = f(T_s)$$



**At**

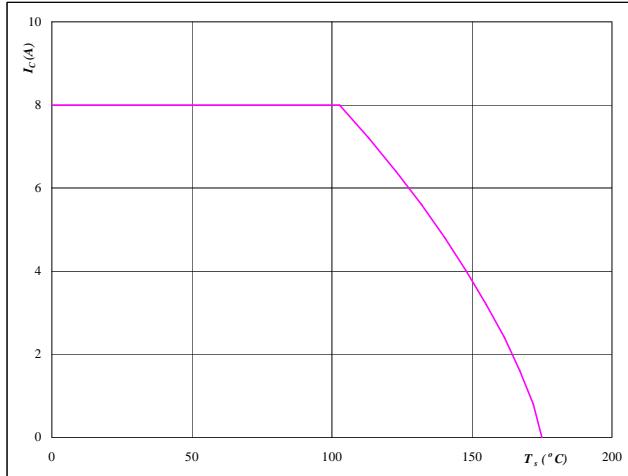
$$T_j = 175 \text{ } ^\circ\text{C}$$

**IGBT**

**figure 14.**

**Collector current as a function of heatsink temperature**

$$I_C = f(T_s)$$



**At**

$$T_j = 175 \text{ } ^\circ\text{C}$$

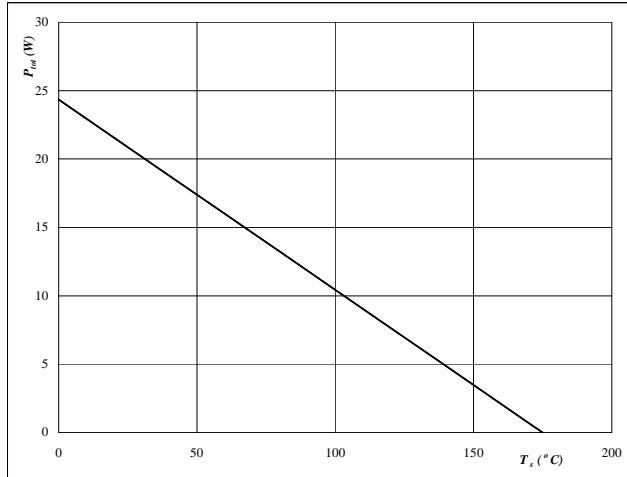
$$U_{CC} = 15 \text{ V}$$

**figure 15.**

**FWD**

**Power dissipation as a function of heatsink temperature**

$$P_{\text{tot}} = f(T_s)$$



**At**

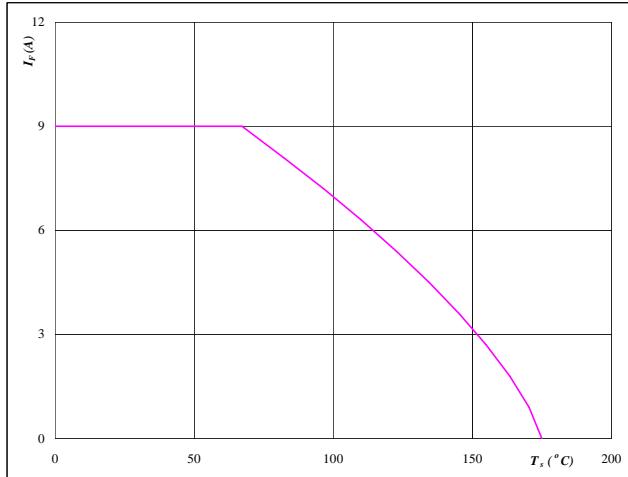
$$T_j = 175 \text{ } ^\circ\text{C}$$

**figure 16.**

**FWD**

**Forward current as a function of heatsink temperature**

$$I_F = f(T_s)$$



**At**

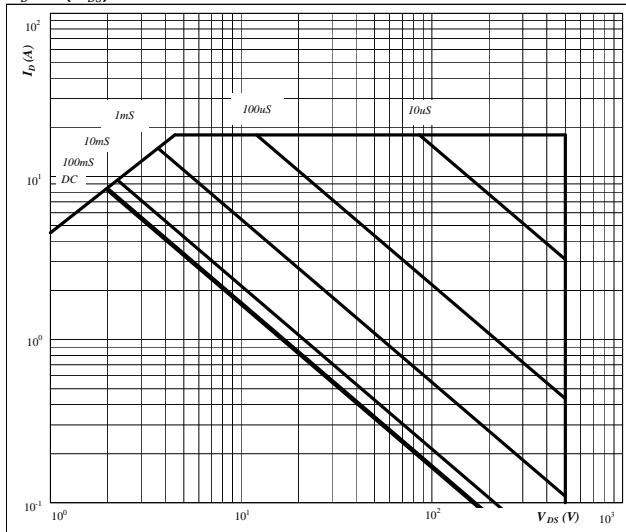
$$T_j = 175 \text{ } ^\circ\text{C}$$

## PFC

**figure 17.** IGBT

**Safe operating area as a function  
of collector-emitter voltage**

$$I_D = f(V_{DS})$$



**At**

$D =$  single pulse

$T_s =$  80 °C

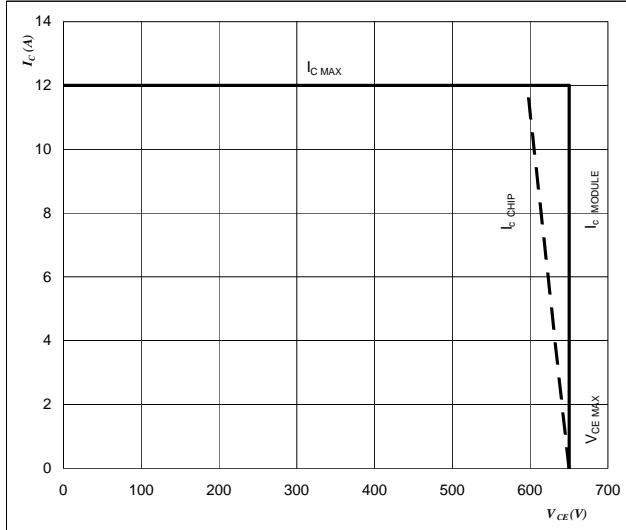
$U_{CC} =$  15 V

$T_j = T_{jmax}$  °C

**figure 18.** IGBT

**Reverse bias safe operating area**

$$I_C = f(V_{CE})$$



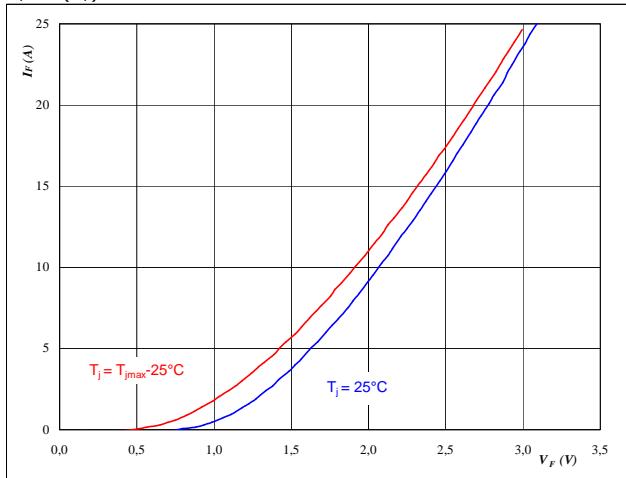
**At**

$T_j = T_{jmax}-25$  °C

## PFC Inverse.Diode

**Figure 1**  
**Typical diode forward current as a function of forward voltage**

$$I_F = f(V_F)$$

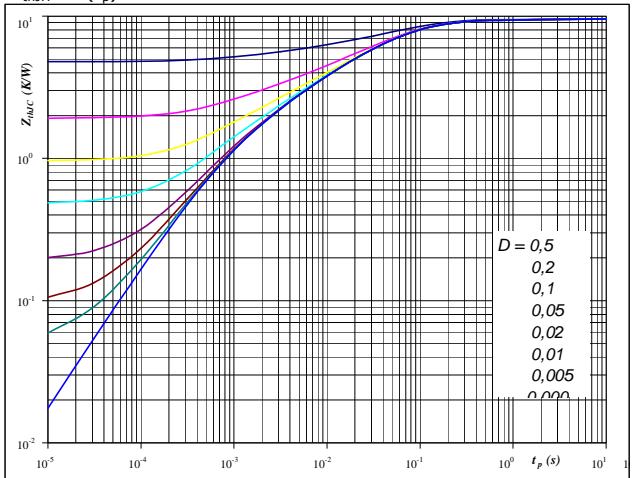


**At**  
 $t_p = 250 \mu\text{s}$

**PFC Inverse.Diode**

**Figure 2**  
**Thyristor transient thermal impedance as a function of pulse width**

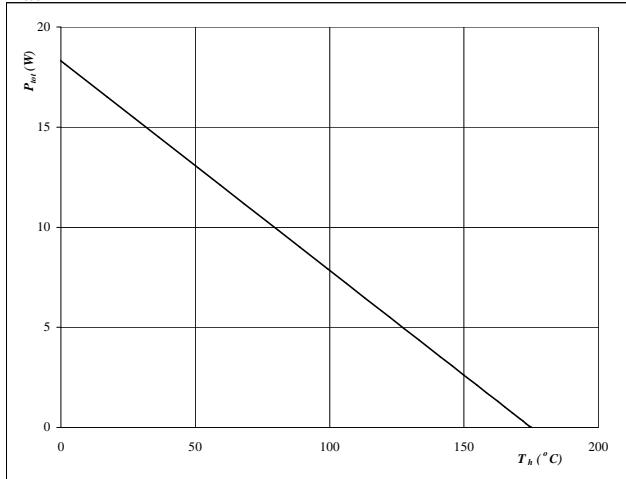
$$Z_{thJH} = f(t_p)$$



**At**  
 $D = t_p / T$   
 Thermal grease  
 $R_{thJH} = 9,56 \text{ K/W}$

**Figure 3**  
**Power dissipation as a function of heatsink temperature**

$$P_{tot} = f(T_h)$$

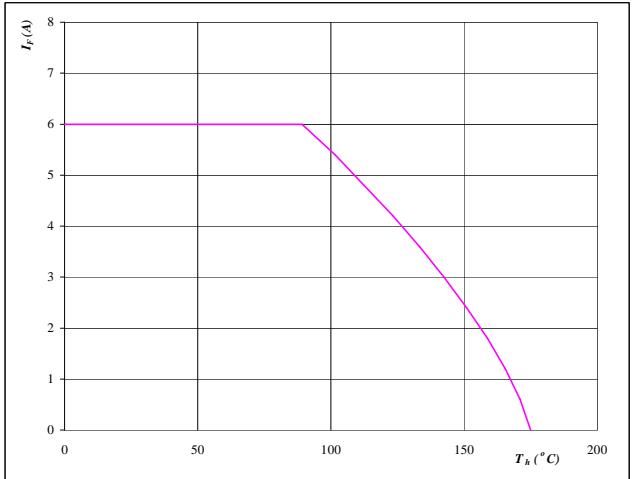


**At**  
 $T_j = 175^\circ\text{C}$

**PFC Inverse.Diode**

**Figure 4**  
**Forward current as a function of heatsink temperature**

$$I_F = f(T_h)$$



**At**  
 $T_j = 175^\circ\text{C}$



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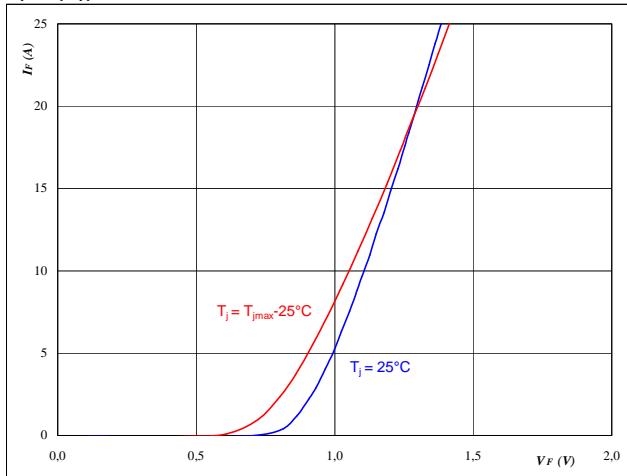
datasheet

## Input Rectifier Diode

**figure 1.****Rectifier Diode**

**Typical diode forward current as  
a function of forward voltage**

$$I_F = f(V_F)$$

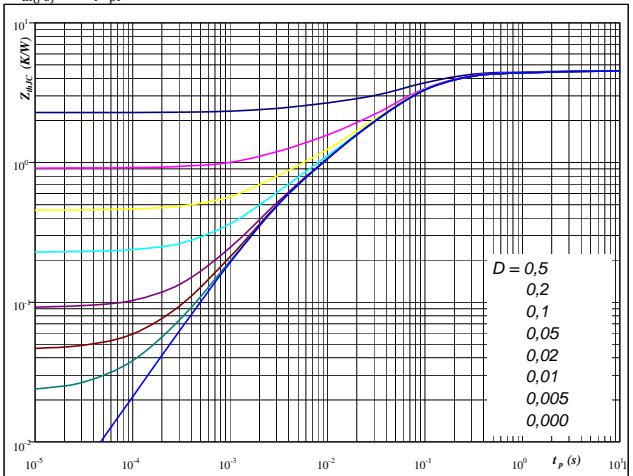
**At**

$$t_p = 250 \mu\text{s}$$

**figure 2.****Rectifier Diode**

**Diode transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$

**At**

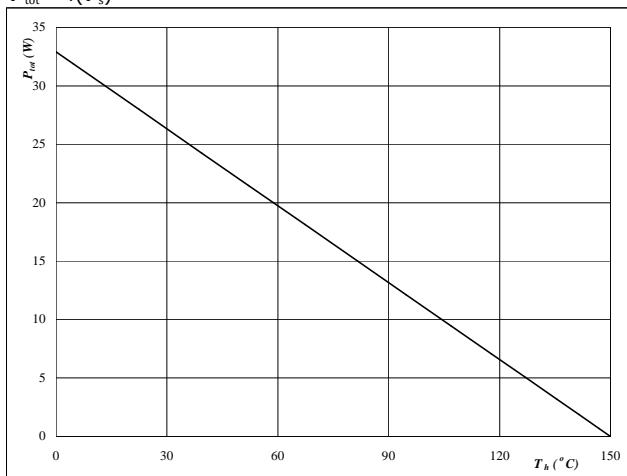
$$D = t_p / T$$

$$R_{th(j-s)} = 4,56 \text{ K/W}$$

**figure 3.****Rectifier Diode**

**Power dissipation as a  
function of heatsink temperature**

$$P_{tot} = f(T_s)$$

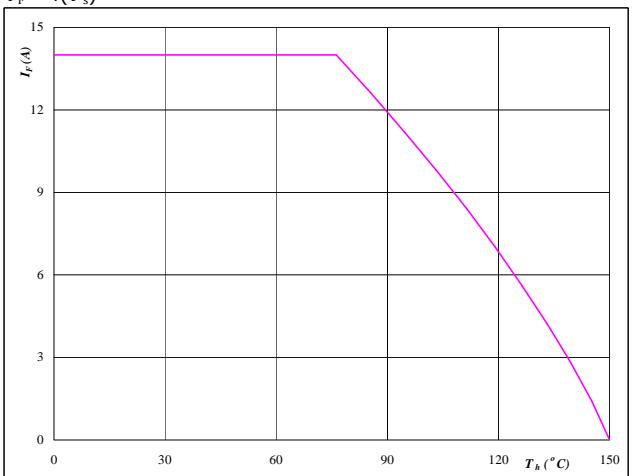
**At**

$$T_j = 150 \text{ °C}$$

**figure 4.****Rectifier Diode**

**Forward current as a  
function of heatsink temperature**

$$I_F = f(T_s)$$

**At**

$$T_j = 150 \text{ °C}$$



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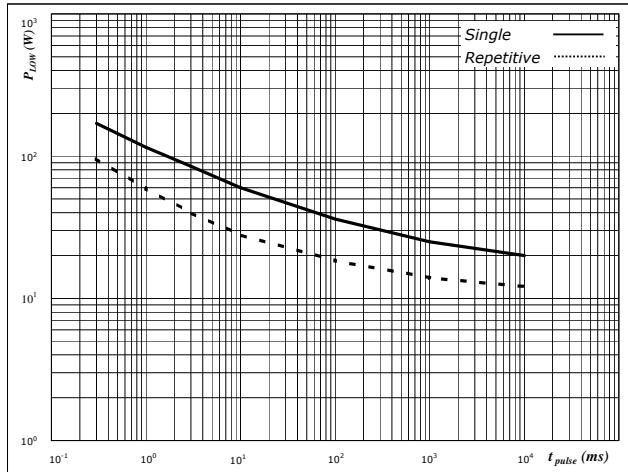
**20-1B06IPB004RC-P952A40**  
**20-PB06IPB004RC-P952A40Y**

datasheet

## Shunt

**figure 1.**

**Pulse Power R1**



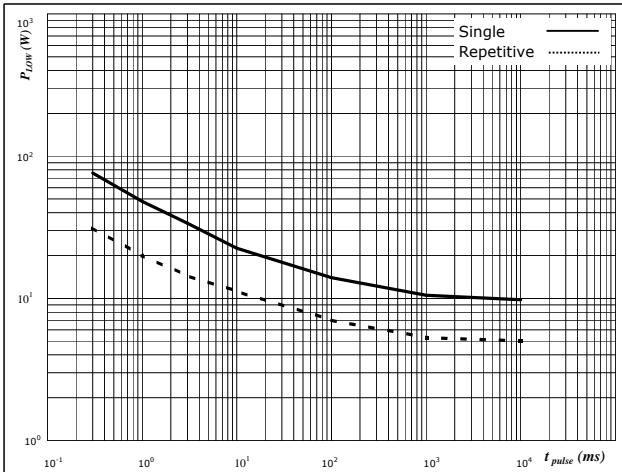
—  $dR/R_0 < 5\%$  after 1 pulse

- - -  $dR/R_0 < 5\%$  after 10.000 cycles; duty cycle < 0,1%

**PFC Shunt**

**figure 2.**

**Pulse Power R2**



—  $dR/R_0 < 1\%$  after 1 pulse

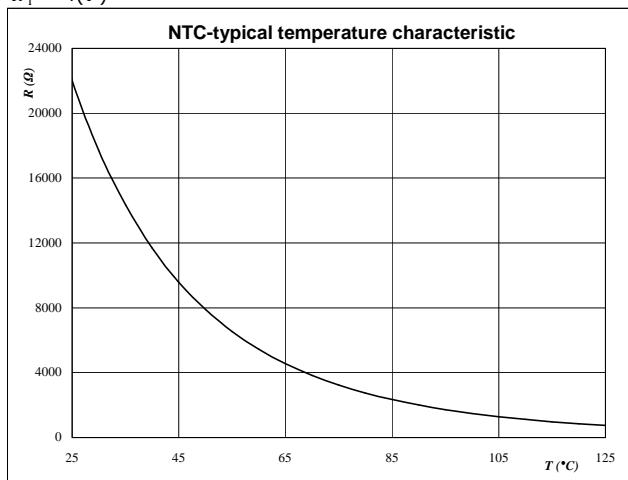
- - -  $dR/R_0 < 1\%$  after 10.000 cycles; duty cycle < 0,1%

## Thermistor

**figure 1.****Thermistor**

**Typical NTC characteristic  
as a function of temperature**

$$R_T = f(T)$$



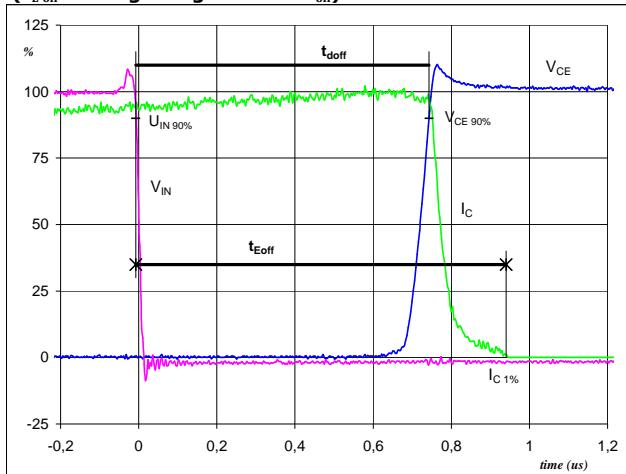
## Switching Definitions Output Inverter

General conditions

$$T_j = 125^\circ C$$

**figure 1.****IGBT**

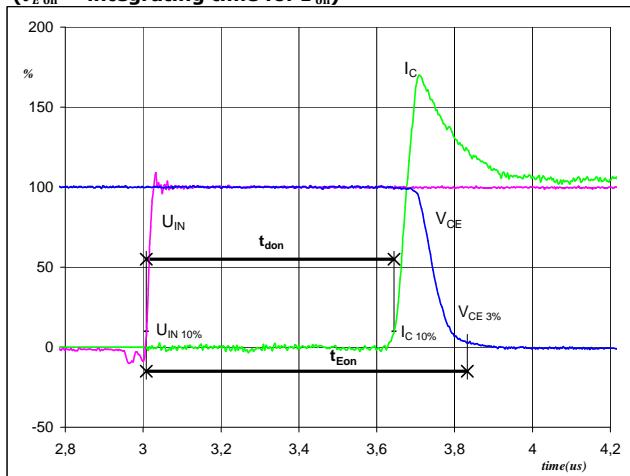
**Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$**   
 $(t_{Eoff} = \text{integrating time for } E_{off})$



$U_{IN\ (0\%)} = 0 \text{ V}$   
 $U_{IN\ (100\%)} = 5 \text{ V}$   
 $V_C\ (100\%) = 400 \text{ V}$   
 $I_C\ (100\%) = 4 \text{ A}$   
 $t_{doff} = 0,75 \mu\text{s}$   
 $t_{Eoff} = 0,95 \mu\text{s}$

**figure 2.****IGBT**

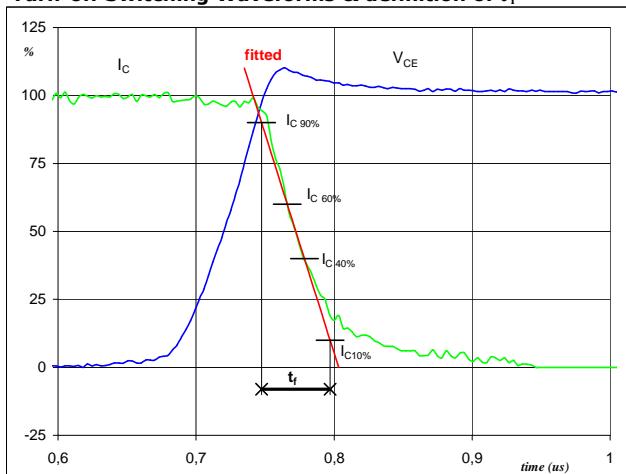
**Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$**   
 $(t_{Eon} = \text{integrating time for } E_{on})$



$U_{IN\ (0\%)} = 0 \text{ V}$   
 $U_{IN\ (100\%)} = 5 \text{ V}$   
 $V_C\ (100\%) = 400 \text{ V}$   
 $I_C\ (100\%) = 4 \text{ A}$   
 $t_{don} = 0,64 \mu\text{s}$   
 $t_{Eon} = 0,82 \mu\text{s}$

**figure 3.****IGBT**

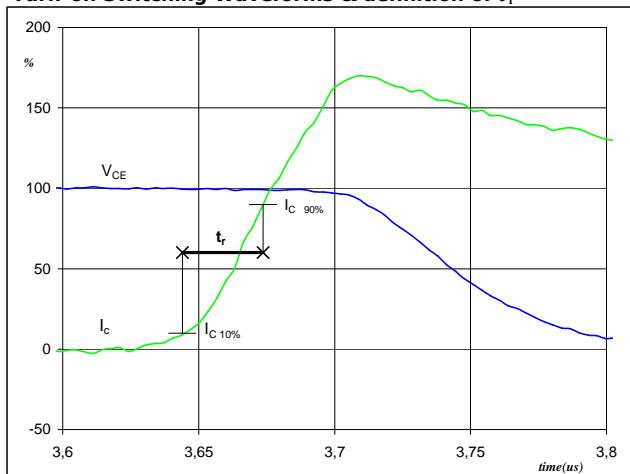
**Turn-off Switching Waveforms & definition of  $t_f$**



$V_C\ (100\%) = 400 \text{ V}$   
 $I_C\ (100\%) = 4 \text{ A}$   
 $t_f = 0,05 \mu\text{s}$

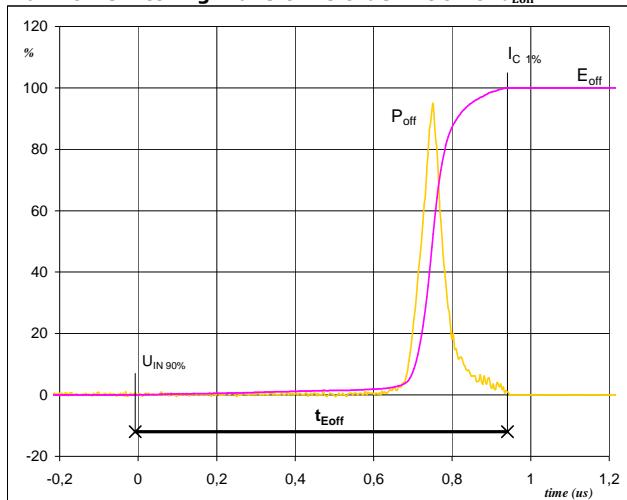
**figure 4.****IGBT**

**Turn-on Switching Waveforms & definition of  $t_r$**

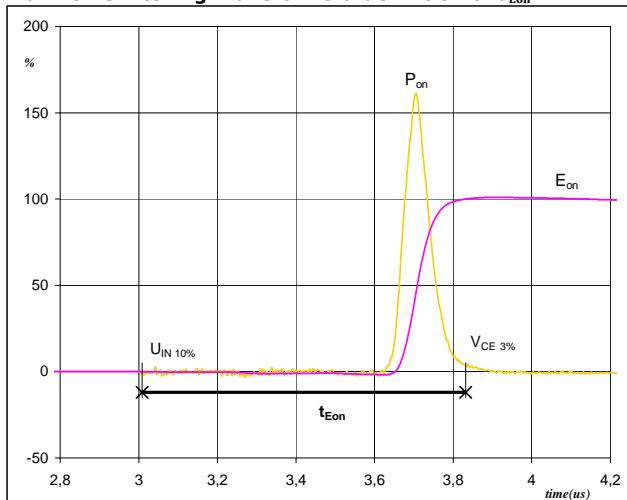


$V_C\ (100\%) = 400 \text{ V}$   
 $I_C\ (100\%) = 4 \text{ A}$   
 $t_r = 0,03 \mu\text{s}$

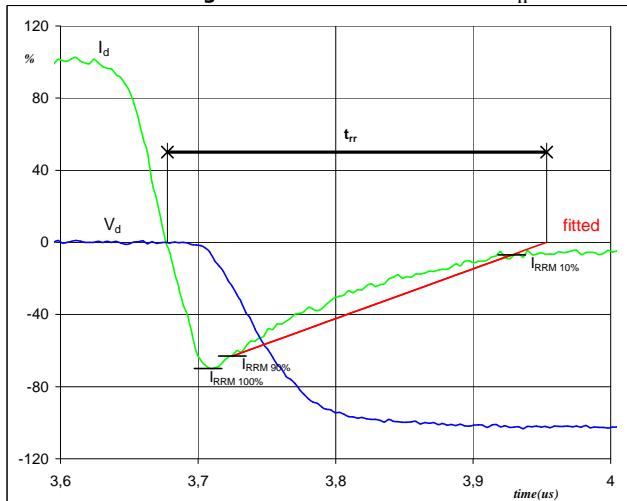
## Switching Definitions Output Inverter

**figure 5.****IGBT****Turn-off Switching Waveforms & definition of  $t_{Eoff}$** 

$P_{off}$  (100%) = 1,61 kW  
 $E_{off}$  (100%) = 0,12 mJ  
 $t_{Eoff}$  = 0,95  $\mu$ s

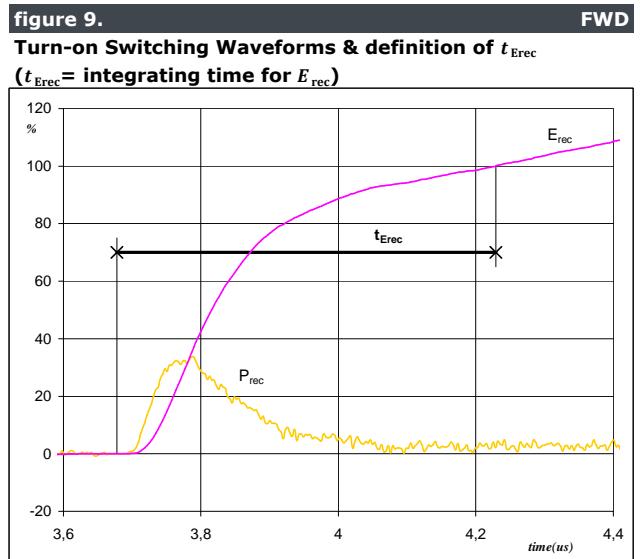
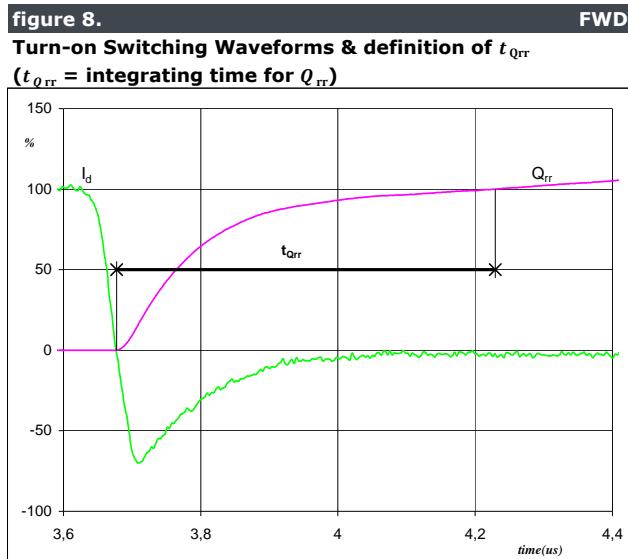
**figure 6.****IGBT****Turn-on Switching Waveforms & definition of  $t_{Eon}$** 

$P_{on}$  (100%) = 1,61 kW  
 $E_{on}$  (100%) = 0,20 mJ  
 $t_{Eon}$  = 0,82  $\mu$ s

**figure 7.****FWD****Turn-off Switching Waveforms & definition of  $t_{rr}$** 

$V_d$  (100%) = 400 V  
 $I_d$  (100%) = 4 A  
 $I_{RRM}$  (100%) = -3 A  
 $t_{rr}$  = 0,25  $\mu$ s

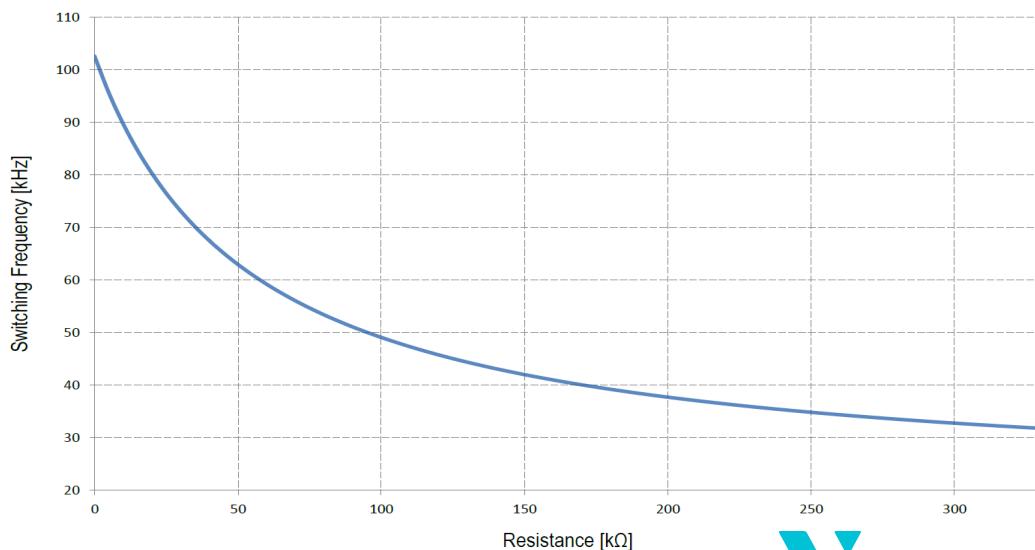
## Switching Definitions Output Inverter



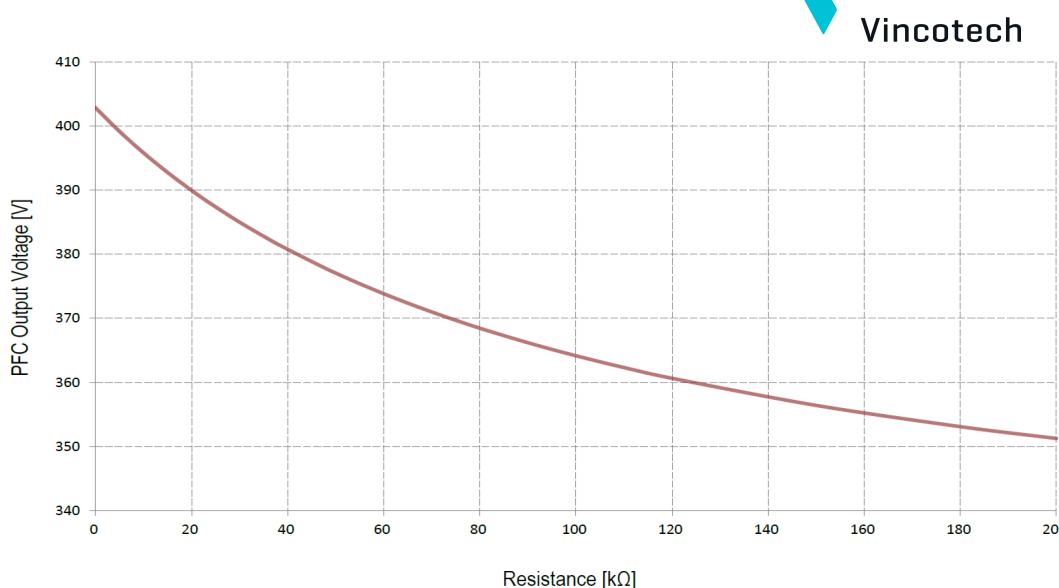
## Application data

### Static logic function table

VCC	VBS	RCIN	ITRIP	ENABLE	FAULT	LO1,2,3	HO1,2,3
<V <sub>CCUV-</sub>	X	X	X	X	0	0	0
15V	<V <sub>BSUV-</sub>	X	0	3.3V	High imp	/LIN1,2,3	0
15V	15V	<3.2V↓	0	3.3V	0	0	0
15V	15V	X	> V <sub>IT,TH+</sub>	3.3V	0	0	0
15V	15V	> V <sub>RCIN,TH</sub>	0	3.3V	High imp	/LIN1,2,3	/HIN1,2,3
15V	15V	> V <sub>RCIN,TH</sub>	0	0	High imp	0	0

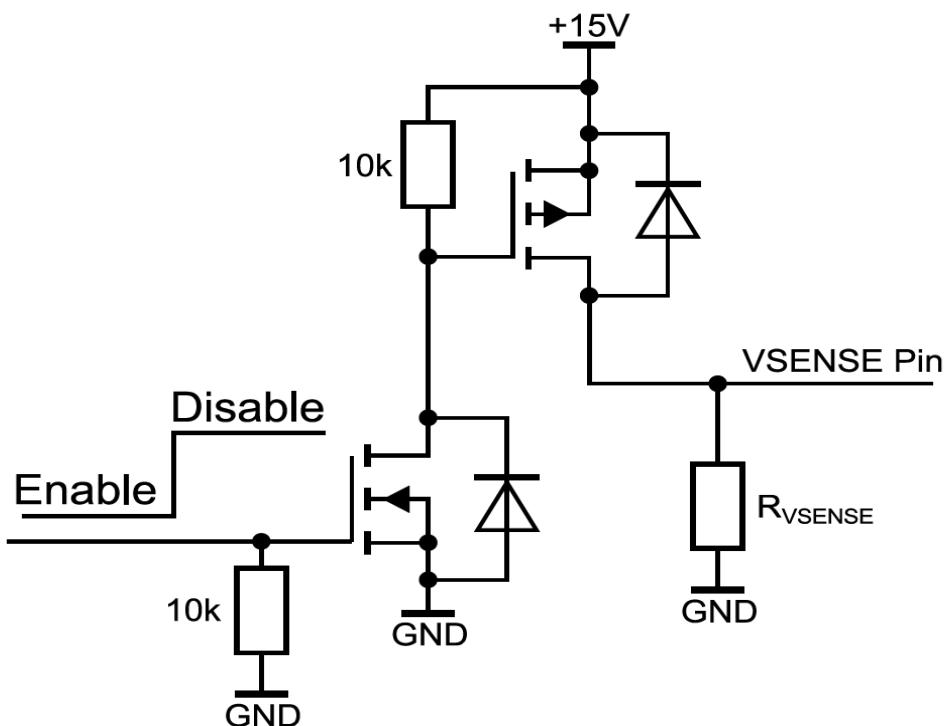


Resistance on f <sub>set</sub>	Switching Frequency
0Ω	102.6kHz
5.1kΩ	95.5kHz
10.0kΩ	89.7kHz
15.0kΩ	84.7kHz
20.0kΩ	80.3kHz
24.0kΩ	77.2kHz
30.0kΩ	73.2kHz
36.0kΩ	69.6kHz
39.0kΩ	68.0kHz
47.0kΩ	64.3kHz
51.0kΩ	62.6kHz
56.0kΩ	60.7kHz
62.0kΩ	58.6kHz
68.0kΩ	56.7kHz
75.0kΩ	54.7kHz
82.0kΩ	52.9kHz
91.0kΩ	50.9kHz
100.0kΩ	49.1kHz
110.0kΩ	47.3kHz
120.0kΩ	45.8kHz
150.0kΩ	42.0kHz
180.0kΩ	39.2kHz
200.0kΩ	37.7kHz



Resistance on V <sub>set</sub>	Output Voltage
0Ω	402.9V
5.1kΩ	399.2V
10.0kΩ	395.9V
15.0kΩ	392.8V
20.0kΩ	390.0V
24.0kΩ	387.9V
30.0kΩ	385.0V
36.0kΩ	382.4V
39.0kΩ	381.2V
47.0kΩ	378.1V
51.0kΩ	376.7V
56.0kΩ	375.1V
62.0kΩ	373.3V
68.0kΩ	371.5V
75.0kΩ	369.7V
82.0kΩ	368.0V
91.0kΩ	366.0V
100.0kΩ	364.2V
110.0kΩ	362.3V
120.0kΩ	360.6V
150.0kΩ	356.4V
180.0kΩ	353.1V
200.0kΩ	351.3V

### PFC enable circuit



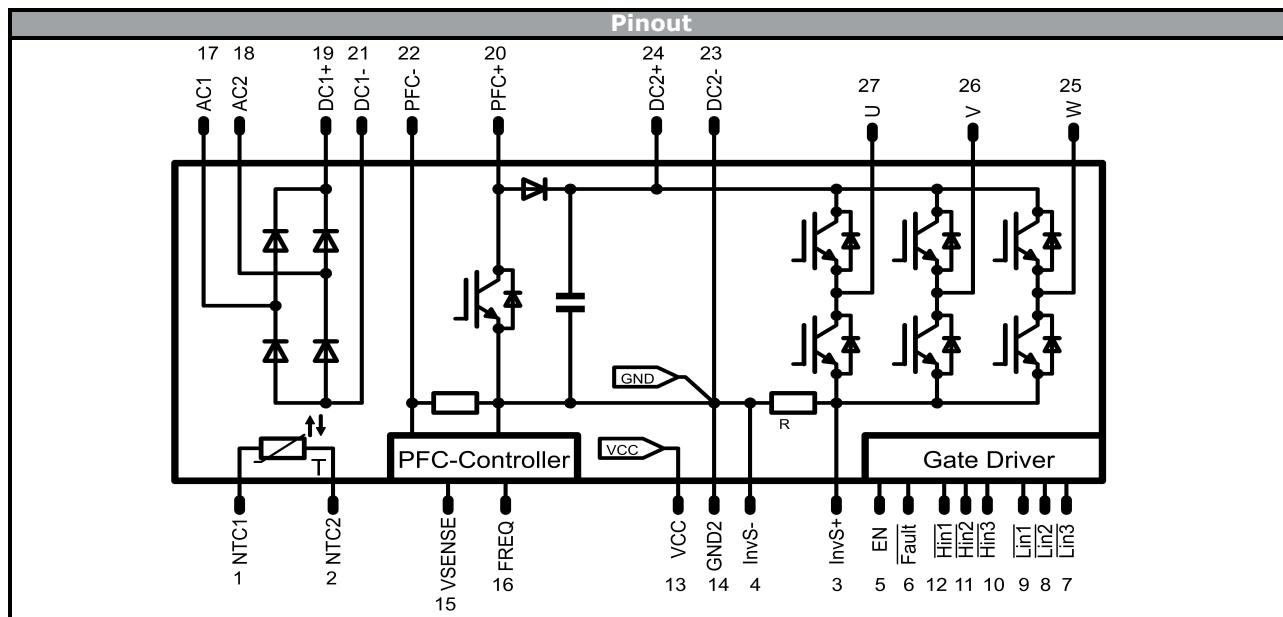
### Pin Descriptions

Pin #	Pin Name	Pin Description
1	NTC2	Temperature sensor connector 1
2	NTC1	Temperature sensor connector 2
3	Invs +	Inverter sense resistor high-side
4	Invs -	Inverter sense resistor low-side
5	EN	Enable I/O functionality
6	$\neg$ Fault	Fault output, indicates over current or under voltage (negative)
7	$\neg$ LIN3	Signal input for low-side W phase
8	$\neg$ LIN2	Signal input for low-side V phase
9	$\neg$ LIN1	Signal input for low-side U phase
10	$\neg$ HIN3	Signal input for high-side W phase
11	$\neg$ HIN2	Signal input for high-side V phase
12	$\neg$ HIN1	Signal input for high-side U phase
13	V <sub>CC</sub>	Driver circuit supply voltage
14	GND2	Inverter ground
15	VSENSE	PFC Bulk voltage sense
16	FREQ	PFC Switching frequency adjust
17	AC1	Rectifier input
18	AC2	Rectifier input
19	DC1 + (coil)	Rectifier output DC +
20	PFC + (coil)	PFC coil connector
21	DC1 -	Rectifier output DC -
22	PFC -	PFC return
23	DC2 -	Inverter input DC -
24	DC2 +	Inverter input DC +
25	W	Output for W phase
26	V	Output for V phase
27	U	Output for U phase

## Ordering Code & Marking - Outline - Pinout

Ordering Code & Marking									
Version			Ordering Code						
without thermal paste, solder pins			20-1B06IPB004RC-P952A40						
with thermal paste, solder pins			20-1B06IPB004RC-P952A40-/3/						
without thermal paste, press fit pins			20-PB06IPB004RC-P952A40Y						
with thermal paste, press fit solder pins			20-PB06IPB004RC-P952A40Y-/3/						
NN-NNNNNNNNNNNN TTTTTTVVVVWWYY UL VIN LLLL SSSS			Text  Datamatrix	Name	Date code	UL & VIN	Lot	Serial	
				NN-NNNNNNNNNNNN-TTTTTV	WWYY	UL VIN	LLLLL	SSSS	
				Type&Ver	Lot number	Serial	Date code		
				TTTTTTV	LLLLL	SSSS	WWYY		

Pin table [mm]				Outline										
Pin	X	Y	Function											
1	45	0	NTC2											
2	42	0	NTC1											
3	39	0	Inv_S+											
4	36	0	Inv_S-											
5	33	0	EN											
6	30	0	FAULT											
7	27	0	LIN3											
8	24	0	LIN2											
9	21	0	LIN1											
10	18	0	HIN3											
11	15	0	HIN2											
12	12	0	HIN1											
13	9	0	VCC											
14	6	0	GND2											
15	3	0	VSENSE											
16	0	0	FREQ											
17	-0,2	26,4	AC1											
18	4,8	26,4	AC2											
19	9,8	26,4	DC1+											
20	14,8	26,4	PFC+											
21	19,8	26,4	DC1-											
22	22,5	26,4	PFC-											
23	25,2	26,4	DC2-											
24	30,2	26,4	DC2+											
25	35,2	26,4	W											
26	40,2	26,4	V											
27	45,2	26,4	U											

**Ordering Code & Marking - Outline - Pinout**


**Identification**

ID	Component	Voltage	Current	Function	Comment
T1,T2,T3,T4,T5,T6	IGBT	600 V	4 A	Inverter Transistor	
T7	IGBT	650 V	15 A	PFC IGBT	
D12	FWD	650 V	15 A	PFC Diode	
D11	FWD	650 V	6 A	PFC inverse Diode	
R3	Resistor			PFC Shunt	
D7,D8,D9,D10	Rectifier	1600 V	12 A	Input Rectifier Diode	
R2	Resistor			DC - Shunt	
C1	Capacitor	500 V		DC link Capacitor	
T	Thermistor			Thermistor	



Vincotech

**20-1B06IPB004RC-P952A40  
20-PB06IPB004RC-P952A40Y**

datasheet

<b>Packaging instruction</b>		>SPQ	Standard	<SPQ	Sample
Standard packaging quantity (SPQ)	<b>100</b>				

<b>Handling instruction</b>
Handling instructions for <i>flow</i> 1B packages see <a href="http://vincotech.com">vincotech.com</a> website.

<b>Package data</b>
Package data for <i>flow</i> 1B packages see <a href="http://vincotech.com">vincotech.com</a> website.

<b>UL recognition and file number</b>
This device is certified according to UL 1557 standard, UL file number E192116. For more information see <a href="http://vincotech.com">vincotech.com</a> website.



<b>Document No.:</b>	<b>Date:</b>	<b>Modification:</b>	<b>Pages</b>
20-xB06IPB004RC-P952A40x-D4-14	08 Apr. 2017	Page number correction	8

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